

## Atlas DCA Pro (Model DCA75) Software Package Revisions

| PC S/W            | Firmware | PC Software Change Details   | Instrument Firmware Change Details  |
|-------------------|----------|--|---|
| V1.1.15.<br>1828  | 0021     | Corrected data import parsing error for saved graphs.  | No change.  |
| V1.1.14.<br>1821  | 0021     | Added graph for BJT: I <sub>C</sub> /I <sub>B</sub> . Corrected issue that caused JFET graph titles to revert to incorrect values when starting a new curve. JFET graph titles corrected in exported data. BJT: I <sub>C</sub> /V <sub>CE</sub> graph now correctly includes leakage current for I <sub>C</sub> axis values. BJT: h <sub>FE</sub> /I <sub>C</sub> graph now correctly includes leakage current for I <sub>C</sub> axis values (h <sub>FE</sub> axis values still takes leakage current into account). Increased range of manually set I <sub>B</sub> test currents available in BJT graphs. Autoset values for V <sub>GE</sub> in IGBT I <sub>C</sub> /V <sub>CE</sub> graph now ensures a good span of I <sub>C</sub> .   | No change.  |
| V.1.1.13.<br>1771 | 0021     | Corrected graph title for JFET $I_D/V_{GS}$ graphs. Corrected missing diode on the diagram for a PNP Darlington with protection diode and base-emitter shunt resistors. Improved text export formatting. Support for new firmware.   | $\label{eq:local_cond} \begin{array}{l} \text{Improved SCR detection for devices with high reverse} \\ \text{conduction.} \\ \text{Added } I_G,  V_{AK},  V_{GK},  I_{LATCH}  \text{and}   I_{HOLD}  \text{measurements for} \\ \text{SCRs.} \end{array}$   |
| V1.1.12.<br>1669  | 0019     | Added Graph for BJT: I <sub>C</sub> /V <sub>BE</sub> .  Improved graph trace drawing order.  Added global graph font size adjustment.  Added labels to PN graph.  Added "spare lead" control selection to PN graph.  Added lock and auto-set for graph parameters.  Added "right-click" option to lock traces (to aid part matching etc.).  Allows swap of Drain/Source for JFET graphs.  Improved Vreg graphs now compensate for voltage dropped across ground current sense resistor.  Improved constant current and constant voltage iteration when close to graph limits.  Added user-defined graph title (useful for printing).  Added user-defined naming of graph traces (with optional auto-numbering that can increment on every graph start).  Added user-defined component names (with optional auto-numbering that can increment on every component identification).  Added option to show/hide graph legend.  Added option to delete all traces on all graphs.  Added graph options to graph menu (in addition to "right-click" context menu).  Added colours to all lead identities.  Added tool-tips of graph parameter limits and other items.  Improved tool-tip behaviour and extended display duration. | IGBT detection improved for very high current devices. Measures $V_{\text{CE(SAT)}}$ saturation voltage for BJTs at $I_{\text{B}}=1\text{mA}$ and $I_{\text{C}}=5\text{mA}$ (displayed if $h_{\text{FE}}>10$ ). Measures $V_{\text{CE(SAT)}}$ saturation voltage for digital transistors at $V_{\text{BE}}=5V$ and $I_{\text{C}}=5\text{mA}$ . Measures $V_{\text{CE(SAT)}}$ saturation voltage for IGBTs at $V_{\text{GE}}=5V$ and $I_{\text{C}}=5\text{mA}$ . Measures $R_{\text{DS(ON)}}$ for JFETs (to $1\Omega$ resolution) at $V_{\text{GS}}=0V$ and $I_{\text{D}}=5\text{mA}$ typically. Measures $R_{\text{DS(ON)}}$ for MOSFETs (to $1\Omega$ resolution) at $V_{\text{GS}}=8V$ and $I_{\text{D}}=5\text{mA}$ typically. Improved constant current and constant voltage iteration when close to test limits. Added SCR reverse conduction rejection test. This helps to reject parts that exhibit SCR-like latch-up. Increased acceptable Germanium leakage current from 2mA to 3mA. Improved detection of Silicon/Germanium semiconductor type for BJTs which helps with some silicon power transistors that have a very low $V_{\text{BE}}$ . Increased regulator quiescent current limit from 5mA to 6mA. Increased regulator dVout limit from 10% to 20% (to help cope with regulators that are less stable when tested on the DCA75). Displays warning if regulator dVout>5%. |
| V1.1.11.<br>1294  | 0018     | Added clearer parameter labels for V/I graphs. Added dVout descriptions in text pane for regulators. Streamlined software download process. Streamlined firmware upgrade process. Improvement in speed of some graph types.  | JFET $I_{DSS}$ measurement now at defined for $V_{DS}$ of $3V$ . JFET and MOSFET Transconductance measurement now at constant $V_{DS}$ of $3V$ . JFET and MOSFET $I_{D(OFF)}$ threshold is now $5\mu A$ . Improved "Digital Level" transistor support.  |
| V1.1.10.<br>1270  | 0017     | Support for new firmware   | Correction of firmware upgrade process for early revision units.  |
| V1.1.9.<br>1263   | 0016     | Added dVout measurement for regulators. Support for new firmware.  | Improved regulator support for some with unstable Vout. Added dVout measurement for regulators. Improved diode network detections. Added new diode network symbols. Improved asymmetric JFET detection.   |
|                   | 0015     | Support for new firmware.  | Update to LCD code to support different LCD chip set.   |
| V1.1.8.<br>1166   | 0014     | Support for new firmware.  | Improved support for MOSFETs with high R <sub>DSon</sub> . Improved support for MOSFETs with high body diode voltage. Improved support for protected-gate IGBTs. Improved Depletion/Enhancement mode differentiation.   |
| V1.1.7.<br>1126   | 0013     | Corrected graph tool-tips for different localisations. Support for new firmware.   | Improved IGBT detection. Improved SCR and Triac detection especially for very sensitive types. Improved performance of boost converter when running   |

|                 |        |   | on battery power.  |
|-----------------|--------|---|--|
| V1.1.6.<br>1115 | 0012   | Support for new firmware.   | Improved detection of germanium transistors that have high reverse collector-emitter leakage current. Correction of diode network detection. Improved SCR and Triac detection.   |
| V1.1.5.985      | 0011   | Added symbols for MOSFETs with body diodes. Corrected $I_B$ labels on curve tracing settings. Added $V_{CC}$ , $V_{DD}$ and $V_S$ labels to test circuit diagrams.  | Added symbols for MOSFETs with body diodes. Increased scrolling speed.   |
| V1.1.4.956      | 0010   | $eq:local_continuous_cont$ | Added "digital" transistor support including measurement of both internal resistances.<br>Improved support for MOSFETs with high $R_{DSon}$ .<br>Improved text line spacing.   |
| V1.1.3.924      | 0009   | Improved measurement of germanium leakage during $H_{\text{FE}}$ graphing. Improved graph scaling. Minor label adjustment for text entry.   | No change.   |
| V1.1.2.840      | 0009   | Support for new firmware.   | LCD initialisation optimisation. Improved depletion mode support. Improved voltage regulator support. JFET PN junction threshold adjustment for improved SiC support.  |
| V1.1.1.834      | 0008   | Improved USB disconnection handling.  |  |
| V1.1.0.815      | 8000   | Added config option to JFET Graphs. Added Graphs: BJT: $h_{FE}/V_{CE}$ BJT: $h_{FE}/I_{C}$ Added multiple traces to JFET $I_D/V_{GS}$ graph. Allow colour change of traces. Added graph printing. Added graph loading & saving. Added circuit diagrams of test conditions.  | Improved MOSFET detection, including support for protected/smart gate types. Improved USB Suspend behaviour. Optimised BJT tests to limit reverse bias to 5V.  |
| V1.0.4.737      | 0007   | Simplified Windows® 8 installation process.  Auto scaling of graphs improved, particularly for small parameters.  | Improved support for bi-colour LEDs that have very symmetrical forward/reverse characteristics.  |
| V1.0.3.720      | 0006   | Includes optional automatic update checking. Support for new firmware.  | Corrected sound on/off settings. Improved support for JFETs with highly non-symmetrical characteristics. Implemented 5mA constant current tests for bipolar transistor $V_{\text{BE}}$ measurements (rather than resistive drive). |
| V1.0.2.0        | 0005   | Improved number format support for international Windows®.  | Improved support for JFETs that have saturation currents of less than 5mA.   |
| V1.0.0.0        | 0004-5 | Original Release.   | Original Release (0005 included mods for factory use only).  |

Upgrades for the DCA75 can be performed by the user. Please contact us if you require assistance. Trademarks shown are property of their respective owners.